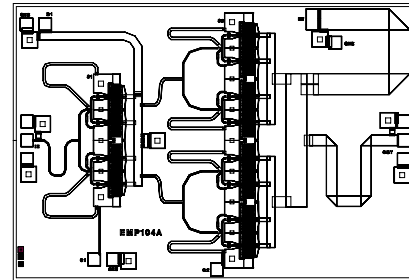


FEATURES

- 5.0 – 6.5 GHz Operating Frequency Range
- 33.0dBm Output Power at 1dB Compression
- 18.0 dB Typical Small Signal Gain
- -44dBc OIMD3 @Each Tone Pout 22dBm

APPLICATIONS

- Point-to-point and point-to-multipoint radio
- Military Radar Systems



Dimension: 2200um X 3230um
 Thickness: 65um $\pm$ 15um



Caution! ESD sensitive device.

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$, 50 ohm, VDD=10V, IDQ=1000mA)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
F	Operating Frequency Range	5.0		6.5	GHz
P1dB	Output Power at 1dB Gain Compression	32.0	33.0		dBm
Gss	Small Signal Gain	16.0	18.0		dB
OIMD3	Output 3 rd Order Intermodulation Distortion @ $\Delta f=10\text{MHz}$, Each Tone Pout 22dBm		-44	-40	dBc
Input RL	Input Return Loss		-8	-6	dB
Output RL	Output Return Loss		-6		dB
Idss	Saturate Drain Current $V_{DS}=3\text{V}$, $V_{GS}=0\text{V}$		1680		mA
VDD	Power Supply Voltage		10		V
Rth	Thermal Resistance (Au-Sn Eutectic Attach)		7		$^\circ\text{C/W}$
Tb	Operating Base Plate Temperature	- 35		+ 80	$^\circ\text{C}$

ABSOLUTE MAXIMUM RATINGS FOR CONTINUOUS OPERATION^{1,2}

SYMBOL	CHARACTERISTIC	VALUE
V_{DS}	Drain to Source Voltage	10V
V_{GS}	Gate to Source Voltage	- 4V
I_{DD}	Drain Current	Idss
I_{GSF}	Forward Gate Current	35 mA
P_{IN}	Input Power	@ 3dB compression
T_{CH}	Channel Temperature	150 $^\circ\text{C}$
T_{STG}	Storage Temperature	-65/150 $^\circ\text{C}$
P_T	Total Power Dissipation	17W

1. Operating the device beyond any of the above rating may result in permanent damage.

2. Bias conditions must also satisfy the following equation $V_{DS} \cdot I_{DS} < (T_{CH} - T_{HS})/R_{TH}$; where T_{HS} = ambient temperature

Specifications are subject to change without notice.

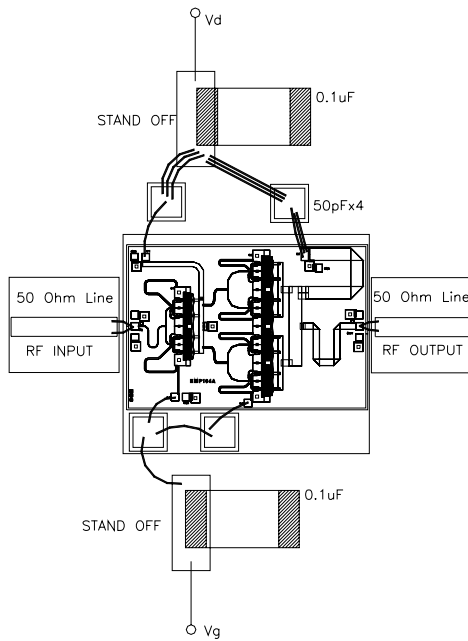
Excelics Semiconductor, Inc. 310 De Guigne Drive, Sunnyvale, CA 94085

Phone: 408-737-1711 Fax: 408-737-1868 Web: www.excelics.com

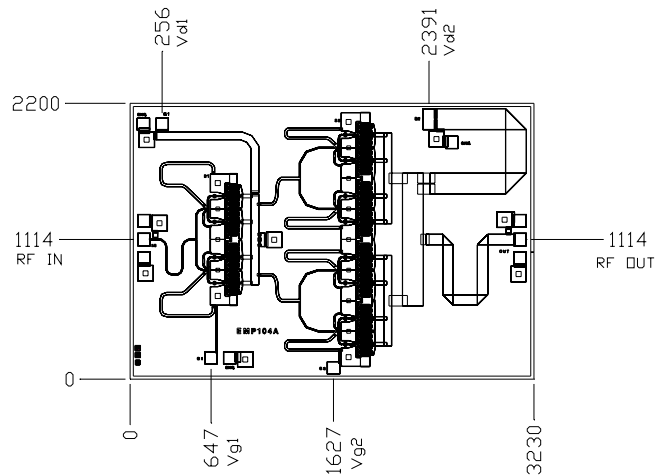
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ASSEMBLY DRAWING

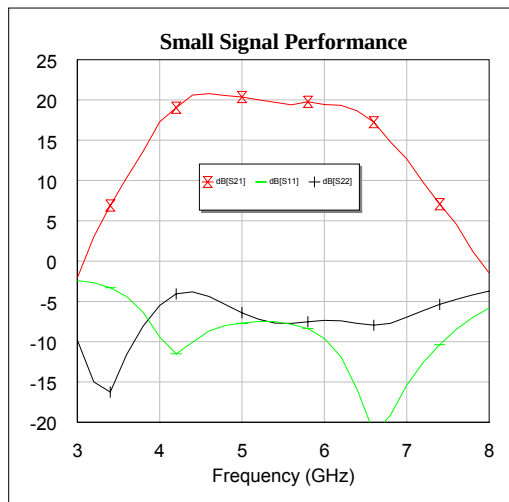
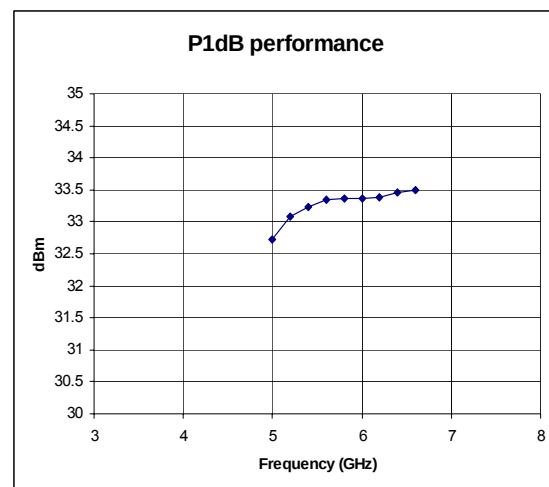


CHIP OUTLINE



All Dimensions in Microns

TYPICAL PERFORMANCE



Data measured @ Vd=10V, Id=950mA

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